



20V PNP LOW SATURATION MEDIUM POWER TRANSISTOR IN SOT26

Features

- $BV_{CEO} > -20V$
- I_C = -3.5A Max Continuous Collector Current
- I_{CM} = -10A Peak Pulse Current
- $R_{CE(SAT)} = 31m\Omega$ for a low equivalent On-Resistance
- Low Saturation Voltage (-70mV max @ 1A/100mA)
- hFE characterized up to -10A for high current gain hold up
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2) Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

Mechanical Data

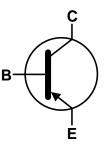
- Case: SOT26
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.015 grams (Approximate)

Applications

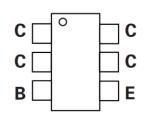
- DC DC Converters
- **Power Management Functions**
- **Power Switches**
- Motor Control







Device Symbol



Pin-Out Top

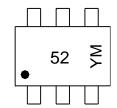
Ordering Information (Note 4)

Product	Compliance	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
ZXTP2006E6TA	AEC-Q101	52	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

Marking Information



52 = Product Type Marking Code YM = Date Code Marking Y or \overline{Y} = Year (ex: C = 2015) M or \overline{M} = Month (ex: 9 = September)

Date Code Key

	Year	2015	2	016	2017	2018	2019	2020	202	1 20	22	2023	2024	2025
Month Jan Feb Mar Apr May Jun Jul Aug Sep Oct Nov I	Code	С		D	Е	F	G	Н		,	J	K	L	М
	Month	1	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code 1 2 3 4 5 6 7 8 9 O N												_		



Absolute Maximum Ratings (@TA = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V _{CBO}	-25	V
Collector-Emitter Voltage	V _{CEO}	-20	V
Emitter-Base Voltage	V _{EBO}	-7.5	V
Continuous Collector Current	Ic	-3.5	Α
Peak Pulse Collector Current	I _{CM}	-10	Α

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)		1.1 8.8	W	
Linear Derating Factor	(Note 6)	- P _D	1.7 13.6	mW/°C	
Thermal Resistance, Junction to Ambient	(Note 5)	В	113		
Thermal Resistance, Junction to Ambient	(Note 6)	$R_{\theta JA}$	73	°C/W	
Thermal Resistance, Junction to Lead	(Note 7)	$R_{ heta JL}$	18.61		
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C		

ESD Ratings (Note 8)

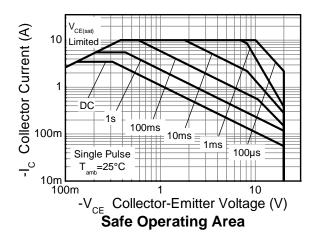
Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	4,000	V	3A
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

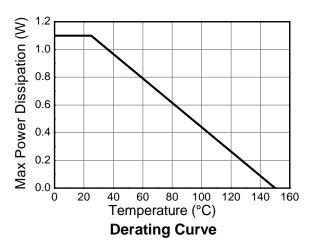
Notes:

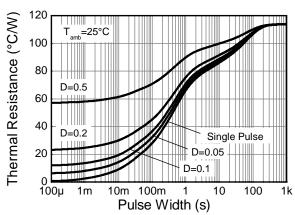
- 5. For a device mounted with collector leads on 25mm x 25mm 1oz copper that is on a single-sided 1.6mm FR4 PCB; device is measured under still air conditions whilst operating in a steady-state.
- 6. Same as note (5), except the device is measured at t ≤ 5secs.
 7. Thermal resistance from junction to solder-point (at the end of the collector leads).
 8. Refer to JEDEC specification JESD22-A114 and JESD22-A115.



Thermal Characteristics and Derating Information







Transient Thermal Impedance



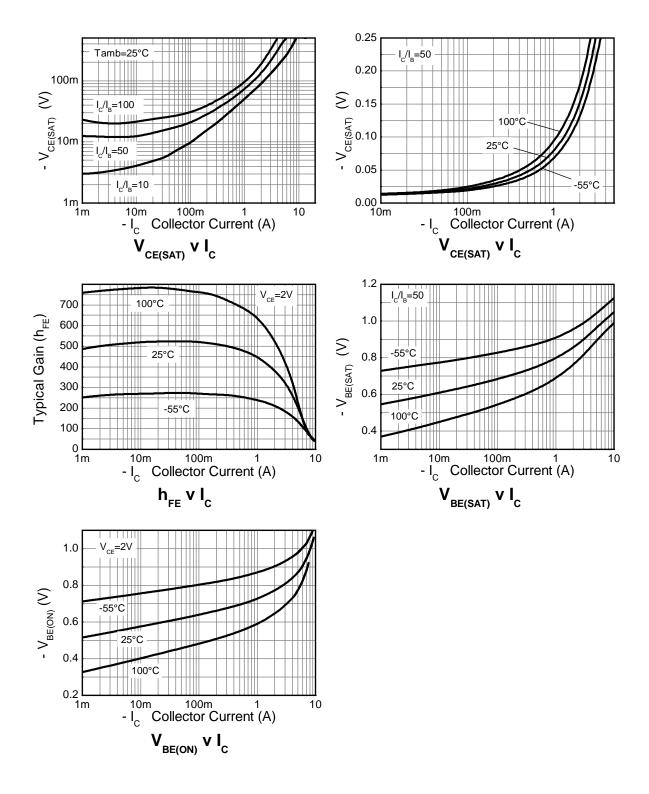
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV _{CBO}	-25	-49		V	$I_C = -100 \mu A$
Collector-Emitter Breakdown Voltage (Note 9)	BV_{CEO}	-20	-43		V	$I_C = -10mA$
Emitter-Base Breakdown Voltage	BV _{EBO}	-7.5	-8.4		V	$I_E = -100 \mu A$
Collector-Base Cutoff Current	I _{CBO}	_	_	-100	nA	V _{CB} = -20V
Emitter Cutoff Current	I _{EBO}	_	_	-100	nA	V _{EB} = -6V
Collector-Emitter Cutoff Current	ICES	_	_	-100	nA	V _{CES} = -20V
ON CHARACTERISTICS (Note 9)						
	h _{FE}	300	575		_	$I_C = -10$ mA, $V_{CE} = -2$ V
DC Current Gain		300	450	900	_	$I_{C} = -1A, V_{CE} = -2V$
DC Current Gain		150	285	_	_	$I_C = -3.5A, V_{CE} = -2V$
		10	40		_	$I_{C} = -10A, V_{CE} = -2V$
	V _{CE(sat)}	_	-10	-15	mV	$I_C = -100 \text{mA}, I_B = -10 \text{mA}$
Collector-Emitter Saturation Voltage		_	-100	-140		$I_C = -1A$, $I_B = -10mA$
		1	-110	-130		$I_C = -3.5A$, $I_B = -350mA$
Base-Emitter Saturation Voltage	V _{BE(sat)}		-0.96	-1.1	V	$I_C = -3.5A$, $I_B = -350mA$
Base-Emitter Turn-On Voltage	V _{BE(on)}	_	-0.8	-0.9	V	I _C = -3.5A, V _{CE} = -2V
SMALL SIGNAL CHARACTERISTICS						
Current Gain-Bandwidth Product	f _T		110		MHz	$V_{CE} = -10V, I_{C} = -50mA, f = 50MHz$
Output Capacitance	C _{obo}	_	45	_	pF	V _{CB} = -10V, f = 1MHz

Note: 9. Measured under pulsed conditions. Pulse width $\leq 300 \mu s$. Duty cycle $\leq 2\%$.



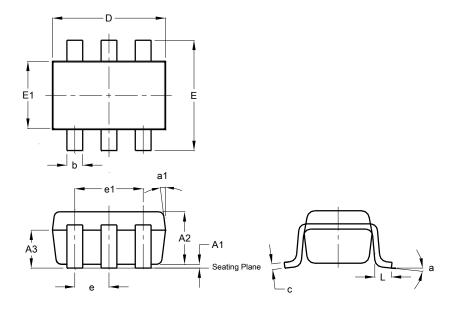
Typical Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)





Package Outline Dimensions

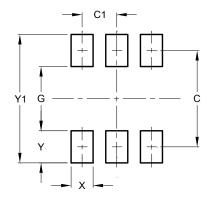
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for the latest version.



	SOT26							
Dim	Min	Max	Тур					
A1	0.013	0.10	0.05					
A2	1.00	1.30	1.10					
A3	0.70	0.80	0.75					
b	0.35	0.50	0.38					
С	0.10	0.20	0.15					
D	2.90	3.10	3.00					
е	-	-	0.95					
e1	-	-	1.90					
Е	2.70	3.00	2.80					
E1	1.50	1.70	1.60					
L	0.35	0.55	0.40					
а	-	-	8°					
a1	-	-	7°					
All	All Dimensions in mm							

Suggested Pad Layout

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
С	2.40
C1	0.95
G	1.60
Х	0.55
Υ	0.80
Y1	3.20



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